

BC817-Q series

45 V, 500 mA NPN general-purpose transistors

Rev. 1 — 8 June 2021

Product data sheet

1. General description

NPN general-purpose transistor in a small SOT23 (TO-236AB) Surface-Mounted Device (SMD) plastic package.

Table 1. Product overview

Type number	Package	PNP complement		
	Nexperia	JEDEC	JEITA	
BC817-Q	SOT23	TO-236AB	-	BC807-Q
BC817-16-Q				BC807-16-Q
BC817-25-Q				BC807-25-Q
BC817-40-Q				BC807-40-Q

2. Features and benefits

- High current
- Three current gain selections
- Qualified according to AEC-Q101 and recommended for use in automotive applications

3. Applications

· General-purpose switching and amplification

4. Quick reference data

Table 2. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V_{CEO}	collector-emitter voltage	open base; T _{amb} = 25 °C		-	-	45	V
Ic	collector current	T _{amb} = 25 °C		-	-	500	mA
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms; T _{amb} = 25 °C		-	-	1	Α
h _{FE}	DC current gain		·				
	BC817-Q	V _{CE} = 1 V; I _C = 100 mA T _{amb} = 25 °C	[1]	100	-	600	
	BC817-16-Q		[1]	100	-	250	
	BC817-25-Q		[1]	160	-	400	
	BC817-40-Q		[1]	250	-	600	

[1] pulsed; $t_p \le 300 \ \mu s$; $\delta \le 0.02$



5. Pinning information

Table 3. Pinning

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	В	base	3	С
2	Е	emitter		
3	С	collector		B—
				Ė
			1	sym123

6. Ordering information

Table 4. Ordering information

Table 4. Ordering information							
Package							
Name	Description	Version					
TO-236AB	Plastic surface-mounted package; 3 leads	SOT23					
	Name	Package Name Description					

7. Marking

Table 5. Marking

Type number	Marking code[1]
BC817-Q	6D%
BC817-16-Q	6A%
BC817-25-Q	6B%
BC817-40-Q	6C%

^{[1] % =} placeholder for manufacturing site code

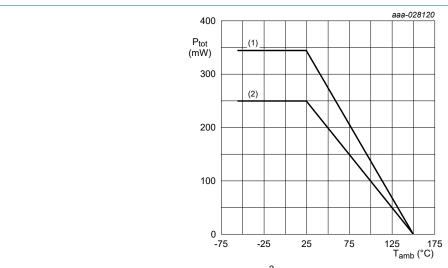
8. Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CBO}	collector-base voltage	open emitter; T _{amb} = 25 °C	-	50	V
V _{CEO}	collector-emitter voltage	open base; T _{amb} = 25 °C	-	45	V
V _{EBO}	emitter-base voltage	open collector; T _{amb} = 25 °C	-	5	V
I _C	collector current	T _{amb} = 25 °C	-	500	mA
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms; T _{amb} = 25 °C	-	1	Α
I _{BM}	peak base current	single pulse; t _p ≤ 1 ms; T _{amb} = 25 °C	-	200	mA
P _{tot}	total power dissipation	$T_{amb} \le 25 ^{\circ}\text{C}$ [1		250	mW
		[3		345	mW
Tj	junction temperature		-	150	°C
T _{amb}	ambient temperature		-65	150	°C
T _{stg}	storage temperature		-65	150	°C

- [1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [2] Valid for all available selection groups.
- [3] Device mounted on an FR4 PCB, single-sided copper, tin-plated; mounting pad for collector 1 cm².



- (1) FFR4 PCB, single-sided copper; 1 cm²
- (2) FR4 PCB, single-sided copper; standard footprint

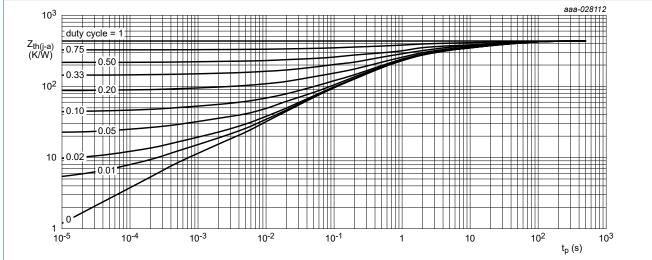
Fig. 1. Power derating curves

9. Thermal characteristics

Table 7. Thermal characteristics

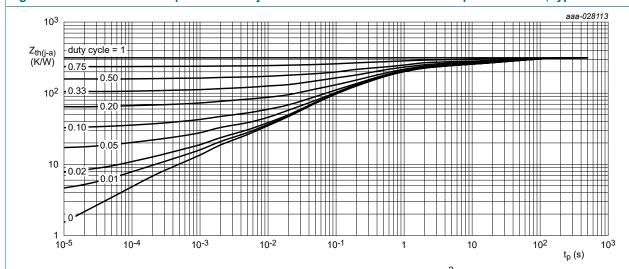
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	[1] [2]	-	-	500	K/W
			[3] [2]	-	-	362	K/W

- [1] Device mounted on an FR4 Printed-Circuit-Board (PCB); single-sided copper; tin-plated and standard footprint.
- [2] Valid for all available selection groups.
- [3] Device mounted on an FR4 PCB, single-sided copper, tin-plated; monting pad for collector 1 cm².



FR4 PCB, single-sided, tin-plated and standard footprint

Fig. 2. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



FR4 PCB, single-sided copper, tin-plated; mounting pad for collector 1 cm².

Fig. 3. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

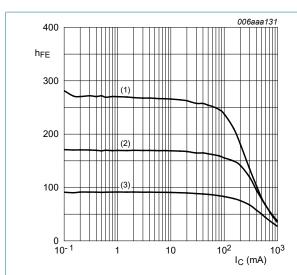
10. Characteristics

Table 8. Characteristics

Parameter	Conditions		Min	Тур	Max	Unit	
collector-base breakdown voltage	I _C = 100 μA; I _E = 0 A; T _{amb} = 25 °C		50	-	-	V	
collector-emitter breakdown voltage	I _C = 10 mA; I _E = 0 A; T _{amb} = 25 °C		45	-	-	V	
emitter-base breakdown voltage	I _E = 100 μA; I _C = 0 A; T _{amb} = 25 °C		5	-	-	V	
collector-base	V _{CB} = 20 V; I _E = 0 A; T _{amb} = 25 °C		-	-	100	nA	
cut-off current	V _{CB} = 20 V; I _E = 0 A; T _j = 150 °C		-	-	5	μΑ	
emitter-base cut-off current	V _{EB} = 5 V; I _C = 0 A; T _{amb} = 25 °C		-	-	100	nA	
DC current gain							
BC817-Q	V _{CE} = 1 V; I _C = 100 mA; T _{amb} = 25 °C	[1]	100	-	600		
BC817-16-Q		[1]	100	-	250		
BC817-25-Q		[1]	160	-	400		
BC817-40-Q		[1]	250	-	600		
DC current gain	V _{CE} = 1 V; I _C = 500 mA; T _{amb} = 25 °C	[1]	40	-	-		
collector-emitter saturation voltage	$I_C = 500 \text{ mA}; I_B = 50 \text{ mA}; T_{amb} = 25 \text{ °C}$	[1]	-	-	700	mV	
base-emitter voltage	V _{CE} = 1 V; I _C = 500 mA; T _{amb} = 25 °C	[1] [2]	-	-	1.2	V	
transition frequency	V _{CE} = 5 V; I _C = 10 mA; f = 100 MHz; T _{amb} = 25 °C		100	-	-	MHz	
collector capacitance	$V_{CB} = 10 \text{ V}; I_{E} = i_{e} = 0 \text{ A}; f = 1 \text{ MHz};$ $T_{amb} = 25 \text{ °C}$		-	3	-	pF	
	collector-base breakdown voltage collector-emitter breakdown voltage emitter-base breakdown voltage collector-base cut-off current emitter-base cut-off current DC current gain BC817-Q BC817-16-Q BC817-25-Q BC817-40-Q DC current gain collector-emitter saturation voltage base-emitter voltage	collector-base breakdown voltage	collector-base breakdown voltage $I_C = 100 \mu A; I_E = 0 A; T_{amb} = 25 ^{\circ}C$ collector-emitter breakdown voltage $I_C = 10 \text{mA}; I_E = 0 A; T_{amb} = 25 ^{\circ}C$ emitter-base breakdown voltage $I_E = 100 \mu A; I_C = 0 A; T_{amb} = 25 ^{\circ}C$ collector-base cut-off current $V_{CB} = 20 V; I_E = 0 A; T_{amb} = 25 ^{\circ}C$ emitter-base cut-off current $V_{CB} = 20 V; I_C = 0 A; T_{amb} = 25 ^{\circ}C$ DC current gain $V_{CE} = 1 V; I_C = 100 mA; T_{amb} = 25 ^{\circ}C$ BC817-Q BC817-16-Q BC817-40-Q $V_{CE} = 1 V; I_C = 100 mA; T_{amb} = 25 ^{\circ}C$ DC current gain $V_{CE} = 1 V; I_C = 500 mA; T_{amb} = 25 ^{\circ}C$ DC current gain $V_{CE} = 1 V; I_C = 500 mA; T_{amb} = 25 ^{\circ}C$ collector-emitter saturation voltage $V_{CE} = 1 V; I_C = 500 mA; T_{amb} = 25 ^{\circ}C$ base-emitter voltage $V_{CE} = 1 V; I_C = 500 mA; T_{amb} = 25 ^{\circ}C$ transition frequency $V_{CE} = 5 V; I_C = 10 mA; f = 100 \text{MHz}; T_{amb} = 25 ^{\circ}C$ collector capacitance $V_{CB} = 10 V; I_E = i_e = 0 A; f = 1 \text{MHz};$	collector-base breakdown voltage $I_C = 100 \mu A; I_E = 0 A; T_{amb} = 25 ^{\circ}C$ 50 collector-emitter breakdown voltage $I_C = 10 \text{mA}; I_E = 0 A; T_{amb} = 25 ^{\circ}C$ 45 emitter-base breakdown voltage $I_E = 100 \mu A; I_C = 0 A; T_{amb} = 25 ^{\circ}C$ 5 collector-base cut-off current $V_{CB} = 20 V; I_E = 0 A; T_{amb} = 25 ^{\circ}C$ - emitter-base cut-off current $V_{CB} = 5 V; I_C = 0 A; T_{amb} = 25 ^{\circ}C$ - DC current gain $V_{CE} = 1 V; I_C = 100 \text{mA}; T_{amb} = 25 ^{\circ}C$ [1] 100 BC817-40-Q [1] 160 BC817-40-Q [1] 250 DC current gain $V_{CE} = 1 V; I_C = 500 \text{mA}; T_{amb} = 25 ^{\circ}C$ [1] 40 collector-emitter saturation voltage $I_C = 500 \text{mA}; I_B = 50 \text{mA}; T_{amb} = 25 ^{\circ}C$ [1] - base-emitter voltage $V_{CE} = 1 V; I_C = 500 \text{mA}; T_{amb} = 25 ^{\circ}C$ [1] - transition frequency $V_{CE} = 5 V; I_C = 10 \text{mA}; f = 100 \text{MHz}; T_{amb} = 25 ^{\circ}C$ [1] - collector capacitance $V_{CB} = 10 V; I_E = i_E = 0 A; f = 1 \text{MHz};$ -	collector-base breakdown voltage $I_C = 100 \mu A$; $I_E = 0 A$; $T_{amb} = 25 ^{\circ}C$ 50 - collector-emitter breakdown voltage $I_C = 10 \text{mA}$; $I_E = 0 A$; $T_{amb} = 25 ^{\circ}C$ 45 - emitter-base breakdown voltage $I_E = 100 \mu A$; $I_C = 0 A$; $T_{amb} = 25 ^{\circ}C$ 5 - collector-base cut-off current $V_{CB} = 20 V$; $I_E = 0 A$; $T_{amb} = 25 ^{\circ}C$ - - emitter-base cut-off current $V_{CB} = 5 V$; $I_C = 0 A$; $V_{CB} = 25 ^{\circ}C$ - - DC current gain $V_{CE} = 1 V$; $I_C = 100 mA$; $V_{CE} = 100 $	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	

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 $[\]begin{array}{ll} [1] & \text{pulsed; } t_p \leq 300 \; \mu \text{s; } \delta \leq 0.02 \\ [2] & V_{BE} \; \text{decreases by about 2 mV/K with increasing temperature.} \end{array}$



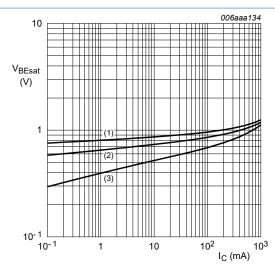
$$V_{CE} = 1 V$$

(1)
$$T_{amb} = 150 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -55 \, ^{\circ}C$$

Fig. 4. BC817-16-Q: DC current gain as a function of collector current; typical values

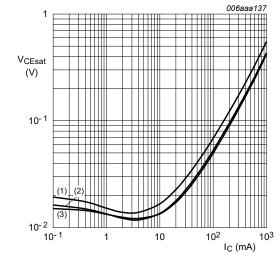


(1)
$$T_{amb} = -55 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = 150 \, ^{\circ}C$$

Fig. 5. BC817-16-Q: Base-emitter saturation voltage as a function of collector current; typical values

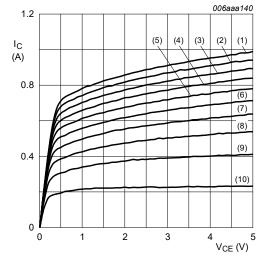


IC/IB = 10

(2)
$$T_{amb}$$
 = 25 °C

(3)
$$T_{amb} = -55 \, ^{\circ}C$$

Fig. 6. BC817-16-Q: Collector-emitter saturation voltage as a function of collector current; typical values



T_{amb} = 25 °C

 $(1) I_B = 16.0 \text{ mA}$

(2) $I_B = 14.4 \text{ mA}$

(3) $I_B = 12.8 \text{ mA}$

(4) $I_B = 11.2 \text{ mA}$

(5) $I_B = 9.6 \text{ mA}$

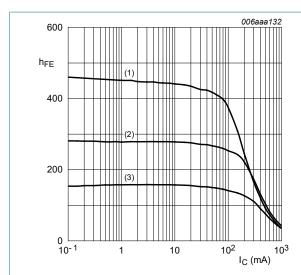
(6) $I_B = 8.0 \text{ mA}$

 $(7) I_B = 6.4 \text{ mA}$

(8) $I_B = 4.8 \text{ mA}$

(9) $I_B = 3.2 \text{ mA}$ (10) $I_B = 1.6 \text{ mA}$

Fig. 7. BC817-16-Q: Collector current as a function of collector-emitter voltage; typical values



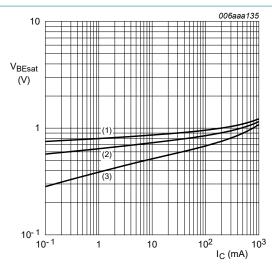
$$V_{CE} = 1 V$$

(1)
$$T_{amb} = 150 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -55 \, ^{\circ}C$$

Fig. 8. BC817-25-Q: DC current gain as a function of collector current; typical values

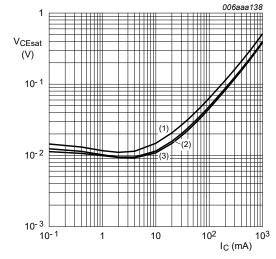


(1)
$$T_{amb} = -55 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = 150 \, ^{\circ}C$$

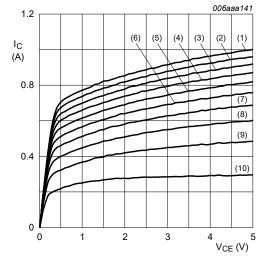
Fig. 9. BC817-25-Q: Base-emitter saturation voltage as a function of collector current; typical values



IC/IB = 10

(3)
$$T_{amb} = -55 \, ^{\circ}C$$

Fig. 10. BC817-25-Q: Collector-emitter saturation voltage as a function of collector current; typical values



T_{amb} = 25 °C

 $(1) I_B = 13.0 \text{ mA}$

(2) $I_B = 11.7 \text{ mA}$

(3) $I_B = 10.4 \text{ mA}$

(4) $I_B = 9.1 \text{ mA}$

 $(5) I_B = 7.8 \text{ mA}$

(6) $I_B = 6.5 \text{ mA}$

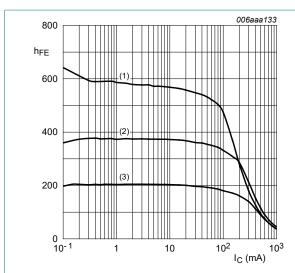
(7) $I_B = 5.2 \text{ mA}$

(8) $I_B = 3.9 \text{ mA}$

(9) $I_B = 2.6 \text{ mA}$

 $(10) I_B = 1.3 mA$

Fig. 11. BC817-25-Q: Collector current as a function of collector-emitter voltage; typical values



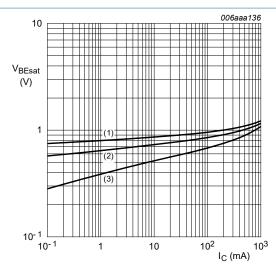
$$V_{CE} = 1 V$$

(1)
$$T_{amb} = 150 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -55 \, ^{\circ}C$$

Fig. 12. BC817-40-Q: DC current gain as a function of collector current; typical values

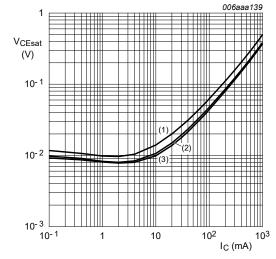


(1)
$$T_{amb} = -55 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = 150 \, ^{\circ}C$$

Fig. 13. BC817-40-Q: Base-emitter saturation voltage as a function of collector current; typical values

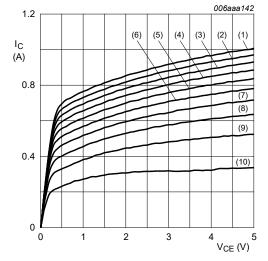


IC/IB = 10

(2)
$$T_{amb}$$
 = 25 °C

(3)
$$T_{amb} = -55 \, ^{\circ}C$$

Fig. 14. BC817-40-Q: Collector-emitter saturation voltage as a function of collector current; typical values



T_{amb} = 25 °C

 $(1) I_B = 12.0 \text{ mA}$

 $(2) I_B = 10.8 \text{ mA}$

 $(3) I_B = 9.6 \text{ mA}$

 $(4) I_B = 8.4 \text{ mA}$

(5) $I_B = 7.2 \text{ mA}$

(6) $I_B = 6.0 \text{ mA}$

(7) $I_B = 4.8 \text{ mA}$

(8) $I_B = 3.6 \text{ mA}$

(9) $I_B = 2.4 \text{ mA}$

 $(10) I_B = 1.2 mA$

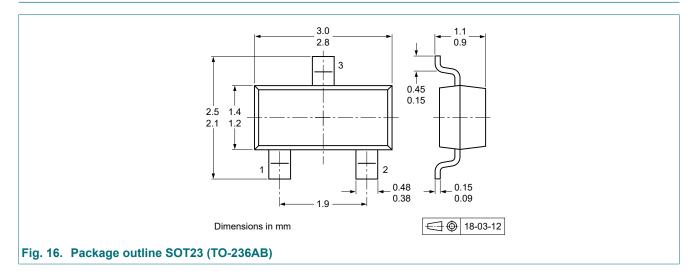
Fig. 15. BC817-40-Q: Collector current as a function of collector-emitter voltage; typical values

11. Test information

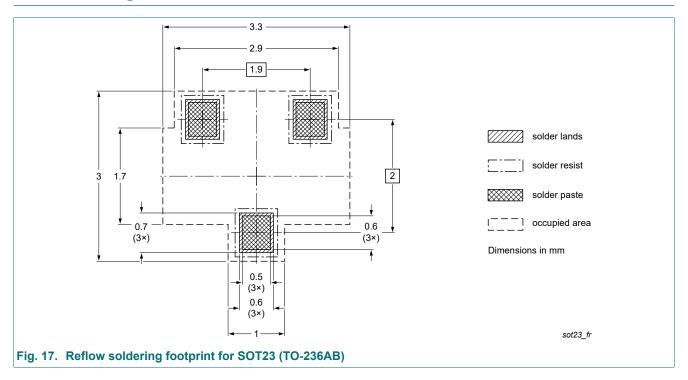
11.1. Quality information

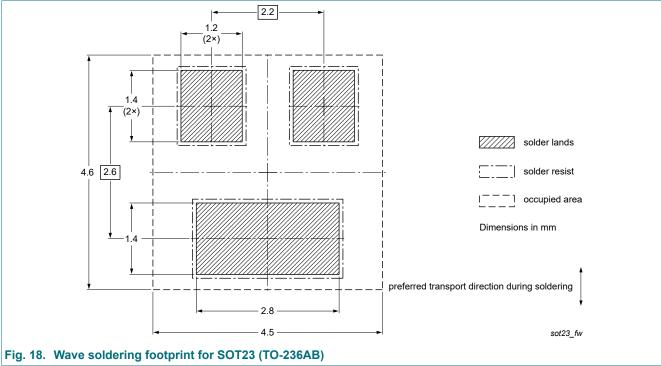
This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101 - Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

12. Package outline



13. Soldering





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14. Revision history

Table 9. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
BC817-Q_SER v.1	20210608	Product data sheet	-	-

Nexperia BC817-Q series

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- 2] The term 'short data sheet' is explained in section "Definitions".
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